

Features

- Operation Voltage Range: 1.65V ~ 5.5V
- Low power current: $I_{CC}=10\mu A(\text{Max})$
- $\pm 24\text{mA}$ output drive ($V_{CC}=3.0\text{V}$)
- Power down protection
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 1000-V Charged-Device Model (C101)
- SOT23-5 Package Available
- SOT353 Package Available

General Description

The 74LVC1G17 is a single Schmitt-trigger buffer, it provides the function $Y=A$.

The device have different input threshold levels for positive-going (V_{T+}) and negative-going (V_{T-}) signals because of the Schmitt-trigger action in the input.

This device has power-down protective circuit, preventing device destruction when it is powered down.

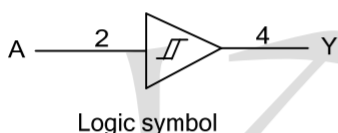
Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks, PDAs
 - Tablet Computers, E-readers
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set-Top Box
 - Cell Phones, Personal Navigation / GPS
 - MP3 Players, Cameras, Video Recorders

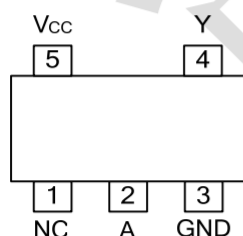
Ordering Information

ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION
74LVC1G17W5-TP	SOT23-5	Tape and Reel,3000
74LVC1G17SE-TP	SOT353	Tape and Reel,3000

Logic Diagram



Pin Configuration



SOT-23-5

SOT-353

Function Table

INPUT	OUTPUT
A	Y
L	H
H	L

Absolute Maximum Ratings

PARAMETER	SYMBOL	TEST CONDITIONS	RATINGS	UNIT
Supply Voltage	V_{CC}		-0.5 ~ 6.5	V
Input Voltage	V_{IN}		-0.5 ~ 6.5	V
Output Voltage	V_{OUT}	Output in the high or low state	-0.5 ~ $V_{CC}+0.5$	V
		Output in the power-off state	-0.5 ~ 6.5	V
Continuous V_{CC} or GND Current	I_{CC}		±100	mA
Continuous Output Current	I_{OUT}		±50	mA
Input Clamp Current	I_{IK}	$V_{IN} < 0$	-50	mA
Output Clamp Current	I_{OK}	$V_{OUT} < 0$	-50	mA
Junction Temperature	T_J		+150	°C
Storage Temperature Range	T_{STG}		-65 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}	Operating	1.65		5.5	V
		Data retention only	1.5			V
Input Voltage	V_{IN}		0		5.5	V
Output Voltage	V_{OUT}	High or low state	0		V_{CC}	V
Operating Temperature	T_A		-40		+125	°C

Thermal Data

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Case	SOT-23-5	θ_{JC}	100	°C/W
	SOT-353		120	

Electrical Characteristics

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Positive-going Input Threshold Voltage	V_{T+}	$V_{CC}=1.65V$	0.76		1.16	V
		$V_{CC}=2.3V$	1.08		1.56	
		$V_{CC}=3.0V$	1.48		1.92	
		$V_{CC}=4.5V$	2.16		2.74	
		$V_{CC}=5.5V$	2.61		3.33	
Negative-going Input Threshold Voltage	V_{T-}	$V_{CC}=1.65V$	0.35		0.62	V
		$V_{CC}=2.3V$	0.56		0.88	
		$V_{CC}=3.0V$	0.84		1.2	
		$V_{CC}=4.5V$	1.41		1.97	
		$V_{CC}=5.5V$	1.87		2.4	
Hysteresis Voltage ($V_{T+}-V_{T-}$)	ΔV_T	$V_{CC}=1.65V$	0.36		0.64	V
		$V_{CC}=2.3V$	0.45		0.78	
		$V_{CC}=3.0V$	0.51		0.87	
		$V_{CC}=4.5V$	0.58		1.04	
		$V_{CC}=5.5V$	0.69		1.11	
High-Level Output Voltage	V_{OH}	$V_{CC}=1.65V\sim 5.5V, I_{OH}=-100\mu A$	$V_{CC}-0.1$			V
		$V_{CC}=1.65V, I_{OH}=-4mA$	1.2			
		$V_{CC}=2.3V, I_{OH}=-8mA$	1.9			
		$V_{CC}=3.0V, I_{OH}=-16mA$	2.4			
		$V_{CC}=3.0V, I_{OH}=-24mA$	2.3			
Low-Level Output Voltage	V_{OL}	$V_{CC}=4.5V, I_{OH}=-32mA$	3.8			V
		$V_{CC}=1.65V\sim 5.5V, I_{OL}=100\mu A$			0.1	
		$V_{CC}=1.65V, I_{OL}=4mA$			0.45	
		$V_{CC}=2.3V, I_{OL}=8mA$			0.3	
		$V_{CC}=3.0V, I_{OL}=16mA$			0.4	
Input Leakage Current	$I_{I(LEAK)}$	$V_{CC}=0\sim 5.5V, V_{IN}=V_{CC}$ or GND			± 5	μA
		$V_{CC}=0V, V_{IN}$ or $V_{OUT}=5.5V$			± 10	
Power OFF Leakage Current	I_{OFF}	$V_{CC}=0V, V_{IN}$ or $V_{OUT}=5.5V$			± 10	μA
Quiescent Supply Current	I_Q	$V_{CC}=1.65V\sim 5.5V, V_{IN}=V_{CC}$ or GND $I_{OUT}=0$			10	μA
Additional Quiescent Supply Current	ΔI_Q	$V_{CC}=3V\sim 5.5V$, One input at $V_{CC}-0.6V$, other inputs at V_{CC} or GND			500	μA
Input Capacitance	C_{IN}	$V_{CC}=3.3V, V_{IN}=V_{CC}$ or GND		4.5		pF

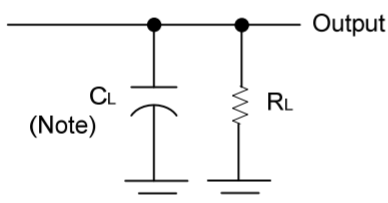
Dynamic Characteristics (Input: $t_R, t_F \leq 3ns$; $P_{RR} \leq 1MHz$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Propagation delay from input (A) to output (Y)	t_{PLH} / t_{PHL}	$C_L=15pF$	$V_{CC}=1.8\pm 0.15V$	2.8	13	ns
			$V_{CC}=2.5\pm 0.2V$	1.6	9.1	ns
			$V_{CC}=3.3\pm 0.3V$	1.5	8.2	ns
			$V_{CC}=5\pm 0.5V$	0.9	6.8	ns
		$C_L=30$ or $50pF$	$V_{CC}=1.8\pm 0.15V$	3.8	14.5	ns
			$V_{CC}=2.5\pm 0.2V$	2	11.1	ns
			$V_{CC}=3.3\pm 0.3V$	1.8	10.2	ns
			$V_{CC}=5\pm 0.5V$	1.2	8.3	ns

Operating Characteristics

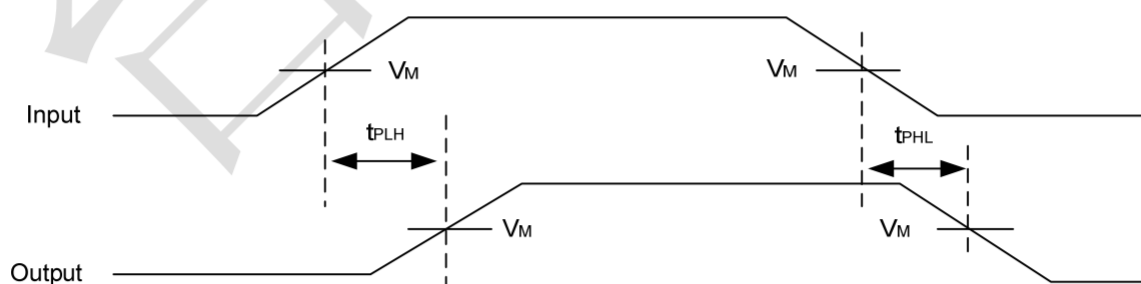
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C_{PD}	$V_{CC}=1.8V$		20		pF
		$V_{CC}=2.5V$		21		pF
		$V_{CC}=3.3V$		22		pF
		$V_{CC}=5V$		25		pF

Test Circuit And Waveforms



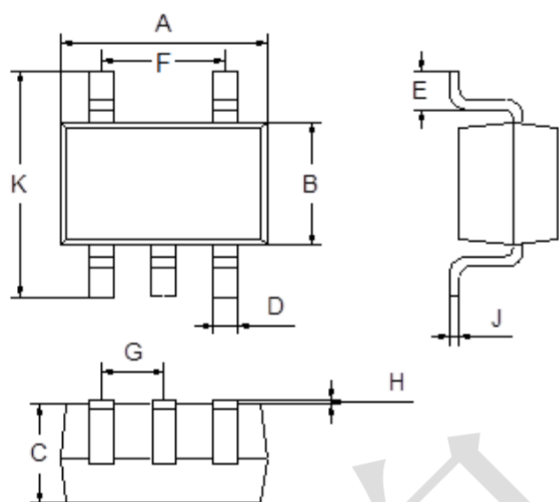
Note: C_L includes probe and jig capacitance.

V_{CC}	V_{IN}	t_R, t_F	V_M	C_L	R_L
$1.8V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	15pF	1M Ω
$2.5V \pm 0.2V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	15pF	1M Ω
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	1.5V	15pF	1M Ω
$5V \pm 0.5V$	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	15pF	1M Ω
$1.8V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	30pF	1K Ω
$2.5V \pm 0.2V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	30pF	500 Ω
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	1.5V	50pF	500 Ω
$5V \pm 0.5V$	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	50pF	500 Ω



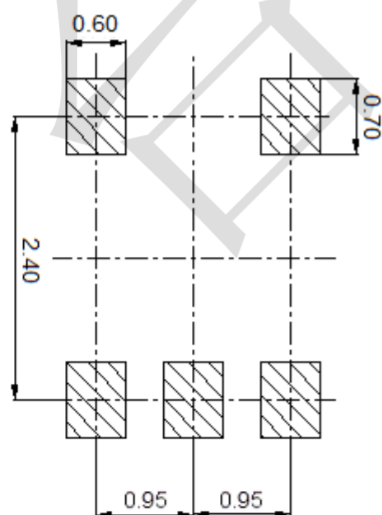
Package Outline Dimensions (Unit: mm)

SOT23-5



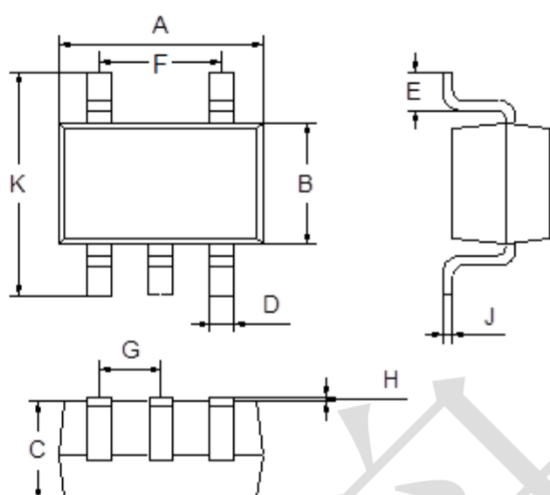
Dimension	Min.	Max.
A	2.80	3.00
B	1.50	1.70
C	1.00	1.20
D	0.35	0.45
E	0.35	0.55
F	1.80	2.00
G	0.90	1.00
H	0.02	0.10
J	0.10	0.20
K	2.60	3.00

Mounting Pad Layout (Unit: mm)



Package Outline Dimensions (Unit: mm)

SOT353



Dimension	Min.	Max.
A	2.00	2.20
B	1.15	1.35
C	0.85	1.05
D	0.15	0.35
E	0.25	0.40
F	1.20	1.40
G	0.60	0.70
H	0.02	0.10
J	0.05	0.15
K	2.20	2.40

Mounting Pad Layout (Unit: mm)

